The Short-Circuit

Current Gain hfe

Consider the common emitter "low-frequency" small-signal model with its output short-circuited.







When the input signal is changing rapidly

Now, contrast this with the results using the **high frequency** model:



Evaluating this circuit, it is evident that the small-signal base current is:

$$i_{b}(\omega) = v_{\pi}(\omega) \left(\frac{1}{r_{\pi}} + j\omega \left(C_{\pi} + C_{\mu} \right) \right)$$

While the small-signal collector current is:

$$i_c(\omega) = v_{\pi}(\omega) (g_m - j\omega C_{\mu})$$

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Here's something you did not know

Therefore, the ratio of small-signal collector current to small-signal base

current is:



Typically, we find that $g_m \gg \omega C_u$, so that we find:

$$\frac{i_c(w)}{i_b(w)} \approx \frac{r_{\pi} g_m}{1 + jw r_{\pi} (C_{\mu} + C_{\pi})}$$

and again we know:



Therefore:

 $\frac{i_c(\omega)}{i_b(\omega)} \approx \frac{\beta}{1 + j\omega r_{\pi} (C_{\mu} + C_{\pi})}$

Your BJT is frequency dependent!

We define this ratio as the small-signal BJT (short-circuit) current gain, $h_{f_e}(\omega)$:

$$h_{f_e}(\omega) \doteq \frac{i_c(\omega)}{i_b(\omega)} \approx \frac{\beta}{1 + j\omega r_{\pi} \left(C_{\mu} + C_{\pi} \right)}$$

Note this function is a low-pass function, were we can define a 3dB break frequency as:



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Note then for frequencies greater than this break frequency:

$$h_{f_e}(w) = \frac{\beta}{1 + j w w_{\beta}}$$
$$\approx j \frac{\beta w_{\beta}}{w} \qquad w > w_{\beta}$$

Note then that $|h_{fe}(\omega)| = 1$ when $\omega = \beta w_{\beta}$.

We can thus define this frequency as w_{τ} , the **unity-gain** frequency:

$$\omega_{\tau} \doteq \beta \omega_{\beta}$$





